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R&S®NRP USB and LAN Power Sensors Specifications





ROHDE&SCHWARZ

Test & Measurement

Data Sheet | 03.00

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Definitions

Product data applies under the following conditions:

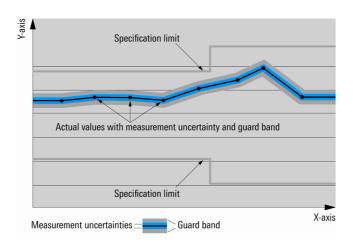
- Three hours storage at the expected operating temperature followed by 30 minutes warm-up, unless otherwise stated
- Specified environmental conditions met
- · Recommended calibration interval adhered to
- · All internal automatic adjustments performed, if applicable

Specifications with limits

Describe warranted product performance by means of a range of values for the specified parameter. These specifications are marked with limiting symbols such as <, \leq , >, \geq , \pm , or descriptions such as maximum and minimum.

Specifications in normal print refer to parameters where compliance is ensured by the design or derived from the measurement of related parameters.

Specifications in **bold** print are 100 % tested. Test limits have been narrowed by guard bands to take into account measurement uncertainties, drift and aging, if applicable.



Specifications without limits

Describe warranted product performance by means of a representative value for the specified parameter. Limits are omitted whenever they are not relevant for the specification (e.g. dimensional data).

Typical values (typ.)

Represent the population mean for the given parameter, derived from the design and/or production testing. Typical values are not warranted by Rohde & Schwarz.

Limits of uncertainty

Expanded uncertainties with a coverage factor of 2, calculated from the test assembly specifications and the modeled behavior of the sensor, including environmental conditions, aging, wear and tear, if applicable. The given values represent limits of uncertainty that are met by the Rohde & Schwarz instrument after calibration at a production or service site. Limits of uncertainty (in italics) are defined in EN 60359 and have been determined in line with the rules of the Guide to the Expression of Uncertainty in Measurement (GUM).

Overview of the R&S®NRP power sensors

Sensor type	Frequency range	Power range,	Connector
R&S®		max. average power / peak envelope power	type
Multipath power	er sensors		
NRP8S(N)	10 MHz to 8 GHz	100 pW to 200 mW (–70 dBm to +23 dBm) max. 1 W (AVG) / 2 W (PK, 10 µs)	N (m)
NRP18S(N)	10 MHz to 18 GHz	100 pW to 200 mW (-70 dBm to +23 dBm) max. 1 W (AVG) / 2 W (PK, 10 µs)	N (m)
NRP33S(N)/ NRP33SN-V	10 MHz to 33 GHz	100 pW to 200 mW (-70 dBm to +23 dBm) max. 1 W (AVG) / 2 W (PK, 10 µs)	3.50 mm (m)
NRP40S(N)	50 MHz to 40 GHz	100 pW to 100 mW (–70 dBm to +20 dBm) max. 200 mW (AVG) / 1 W (PK, 10 μs)	2.92 mm (m)
NRP50S(N)	50 MHz to 50 GHz	100 pW to 100 mW (–70 dBm to +20 dBm) max. 200 mW (AVG) / 1 W (PK, 10 μs)	2.40 mm (m)
Thermal power	r sensors		
NRP18T(N)	DC to 18 GHz	300 nW to 100 mW (–35 dBm to +20 dBm) max. 300 mW (AVG) / 20 W (PK, 1 μs)	N (m)
NRP33T(N)	DC to 33 GHz	300 nW to 100 mW (–35 dBm to +20 dBm) max. 300 mW (AVG) / 10 W (PK, 1 μs)	3.50 mm (m)
NRP40T(N)	DC to 40 GHz	300 nW to 100 mW (–35 dBm to +20 dBm) max. 300 mW (AVG) / 10 W (PK, 1 μs)	2.92 mm (m)
NRP50T(N)	DC to 50 GHz	300 nW to 100 mW (–35 dBm to +20 dBm) max. 300 mW (AVG) / 10 W (PK, 1 μs)	2.40 mm (m)
NRP67T(N)	DC to 67 GHz	300 nW to 100 mW (–35 dBm to +20 dBm) max. 300 mW (AVG) / 10 W (PK, 1 μs)	1.85 mm (m)
NRP110T	DC to 110 GHz	300 nW to 100 mW (–35 dBm to +20 dBm) max. 300 mW (AVG) / 10 W (PK, 1 μs)	1.00 mm (m)
Average power	r sensors		
NRP6A(N)	8 kHz to 6 GHz	100 pW to 200 mW (–70 dBm to +23 dBm) max. 1 W (AVG) / 2 W (PK, 10 µs)	N (m)
NRP18A(N)	8 kHz to 18 GHz	100 pW to 200 mW (-70 dBm to +23 dBm) max. 1 W (AVG) / 2 W (PK, 10 µs)	N (m)

Specifications in brief of the R&S®NRP power sensors

Sensor type R&S [®]	Impedance matching (SWR)	Rise time Video BW	Zero offset (typ.)	Noise (typ.)	Uncertainty for p measurements at +20 °C to +25	
			, , ,		absolute (in dB[sk1])	relative (in dB)
Multipath pow	er sensors					
NRP8S(N)	10 MHz to 2.4 GHz: < 1.13 > 2.4 GHz to 8.0 GHz: < 1.20				0.053 to 0.065	0.022 to 0.050
NRP18S(N)	10 MHz to 2.4 GHz: < 1.13 > 2.4 GHz to 8.0 GHz: < 1.20 > 8.0 GHz to 18.0 GHz: < 1.25				0.053 to 0.094	0.022 to 0.069
NRP33S(N)/ NRP33SN-V	10 MHz to 2.4 GHz: < 1.13 > 2.4 GHz to 8.0 GHz: < 1.20 > 8.0 GHz to 18.0 GHz: < 1.25 > 18.0 GHz to 26.5 GHz: < 1.30 > 26.5 GHz to 33.0 GHz: < 1.35	< 5 µs > 100 kHz	_{kHz} 28 pW	20 pW	0.053 to 0.134	0.022 to 0.136
NRP40S(N)	50 MHz to 2.4 GHz: < 1.13 > 2.4 GHz to 8.0 GHz: < 1.20 > 8.0 GHz to 18.0 GHz: < 1.25 > 18.0 GHz to 26.5 GHz: < 1.30 > 26.5 GHz to 33.0 GHz: < 1.35 > 33.0 GHz to 40.0 GHz: < 1.37				0.073 to 0.138	0.028 to 0.142
NRP50S(N)	50 MHz to 2.4 GHz: < 1.13 > 2.4 GHz to 8.0 GHz: < 1.20 > 8.0 GHz to 18.0 GHz: < 1.25 > 18.0 GHz to 26.5 GHz: < 1.30 > 26.5 GHz to 33.0 GHz: < 1.35 > 33.0 GHz to 40.0 GHz: < 1.37 > 40.0 GHz to 50.0 GHz: < 1.40				0.073 to 0.183	0.028 to 0.184

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Sensor type R&S®	Impedance matching (SWR)	Rise time Video BW	Zero offset (typ.)	Noise (typ.)	Uncertainty for power measurements at +20 °C to +25 °C	
			,		absolute (in dB)	relative (in dB)
Thermal power						
NRP18T(N)	DC to 100 MHz: < 1.03 > 100 MHz to 2.4 GHz: < 1.06 > 2.4 GHz to 12.4 GHz: < 1.13 > 12.4 GHz to 18.0 GHz: < 1.16				0.040 to 0.082	0.010
NRP33T(N)	DC to 100 MHz: < 1.03 > 100 MHz to 2.4 GHz: < 1.06 > 2.4 GHz to 12.4 GHz: < 1.13 > 12.4 GHz to 18.0 GHz: < 1.16 > 18.0 GHz to 26.5 GHz: < 1.22 > 26.5 GHz to 33.0 GHz: < 1.28				0.040 to 0.101	0.010
NRP40T(N)	DC to 100 MHz: < 1.03 > 100 MHz to 2.4 GHz: < 1.06 > 2.4 GHz to 12.4 GHz: < 1.13 > 12.4 GHz to 18.0 GHz: < 1.16 > 18.0 GHz to 26.5 GHz: < 1.22 > 26.5 GHz to 40.0 GHz: < 1.28				0.040 to 0.108	0.010
NRP50T(N)	DC to 100 MHz: < 1.03 > 100 MHz to 2.4 GHz: < 1.06 > 2.4 GHz to 12.4 GHz: < 1.13 > 12.4 GHz to 18.0 GHz: < 1.16 > 18.0 GHz to 26.5 GHz: < 1.22 > 26.5 GHz to 40.0 GHz: < 1.28 > 40.0 GHz to 50.0 GHz: < 1.30	_	15 nW	15 nW	0.040 to 0.143	0.010
NRP67T(N)	DC to 100 MHz: < 1.03 > 100 MHz to 2.4 GHz: < 1.06 > 2.4 GHz to 12.4 GHz: < 1.13 > 12.4 GHz to 18.0 GHz: < 1.16 > 18.0 GHz to 26.5 GHz: < 1.22 > 26.5 GHz to 40.0 GHz: < 1.28 > 40.0 GHz to 50.0 GHz: < 1.30 > 50.0 GHz to 67.0 GHz: < 1.35				0.040 to 0.248	0.010
NRP110T	DC to 100 MHz: < 1.05 > 100 MHz to 2.4 GHz: < 1.08 > 2.4 GHz to 12.4 GHz: < 1.18 > 12.4 GHz to 18.0 GHz: < 1.23 > 18.0 GHz to 26.5 GHz: < 1.28 > 26.5 GHz to 40.0 GHz: < 1.38 > 40.0 GHz to 50.0 GHz: < 1.46 > 50.0 GHz to 67.0 GHz: < 1.56 > 67.0 GHz to 80.0 GHz: < 1.60 > 80.0 GHz to 95.0 GHz: < 1.60 > 95.0 GHz to 110 GHz: < 1.70				0.040 to 0.318	0.014

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Sensor type R&S [®]	Impedance matching (SWR)		Rise time Zero Video offset BW (typ.)	Noise (typ.)	Uncertainty for power measurements at +20 °C to +25 °C		
						absolute (in dB)	relative (in dB)
Average power	er sensors						
NRP6A(N)	8 kHz to < 20 kHz: <	< 1.25				0.051 to 0.056	0.022 to 0.050
	20 kHz to 2.4 GHz: <	< 1.13					
	> 2.4 GHz to 6.0 GHz: <	< 1.20					
NRP18A(N)	8 kHz to < 20 kHz: <	< 1.25	_	28 pW	20 pW	0.051 to 0.094	0.022 to 0.069
. ,	20 kHz to 2.4 GHz: <	< 1.13					
	> 2.4 GHz to 8.0 GHz: <	< 1.20					
	> 8.0 GHz to 18.0 GHz: <	< 1.25					

Multipath power sensors

R&S®NRP8S(N)/18S(N)/33S(N) multipath power sensors R&S®NRP33SN-V multipath power sensor for use in thermal vacuum

Specifications from 10 MHz to 8 GHz apply to the R&S®NRP8S(N). Specifications from 10 MHz to 18 GHz apply to the R&S®NRP18S(N). Specifications from 10 MHz to 33 GHz apply to the R&S®NRP33S(N)/33SN-V.

Frequency range	R&S®NRP8S(N)	10 MHz to 8 GHz					
	R&S®NRP18S(N)	10 MHz to 18 GHz					
	R&S®NRP33S(N)/33SN-V	· · ·					
Impedance matching (SWR)	10 MHz to 2.4 GHz	< 1.13 (1.11)					
5 (,	> 2.4 GHz to 8.0 GHz	< 1.20 (1.18)	(): +15 °C to +35 °C				
	> 8.0 GHz to 18.0 GHz	< 1.25 (1.23)	()				
	> 18.0 GHz to 26.5 GHz	< 1.30 (1.28)					
	> 26.5 GHz to 33.0 GHz	< 1.35 (1.33)					
Power measurement range	continuous average	100 pW to 200 mW (–70 c	IBm to +23 dBm)				
· ·	burst average	300 nW to 200 mW (–35 d					
	timeslot/gate average	300 pW to 200 mW (-65 d	IBm to +23 dBm) 1				
	trace	2 nW to 200 mW (-57 dBr	m to +23 dBm) 2				
Max. power	average power	1 W (+30 dBm) AVG, max	. 10 V DC				
·	peak envelope power	2 W (+33 dBm) for max. 1					
Measurement subranges	path 1	-70 dBm to -15 dBm	•				
•	path 2	-53 dBm to +5 dBm					
	path 3	-33 dBm to +23 dBm					
Transition regions	with automatic path selection ³	(-20 ± 1) dBm to (-14 ± 1)) dBm				
		(0 ± 1) dBm to $(+6 \pm 1)$ dB					
Dynamic response	video bandwidth	> 100 kHz (150 kHz)	(): +15 °C to +35 °C				
	rise time 10 %/90 %	< 5 µs (3 µs)					
Acquisition	sample rate (continuous)	2 Msps					
Triggering	internal						
	threshold level range –38 dBm to +23 dBm						
	threshold level accuracy						
	measurements						
	threshold level hysteresis 0 dB to 10 dB						
	dropout ⁴	0 s to 10 s					
	external	EXTernal[1]: R&S®NRP2 or R&S®NRP-Z5					
	EXTernal2: coax		ıl trigger I/0				
	slope (external, internal)	pos./neg.					
	delay	–5 s to +10 s					
	hold-off	0 s to 10 s					
	resolution (delay, hold-off, dropout)	0.5 μs (sample period)					
	source	INTernal, EXTernal[1], EX	Ternal2,				
7	Social at social and an a	IMMediate, BUS, HOLD					
Zero offset	initial, without zeroing		_				
	path 1	< 250 [235] (50) pW					
	path 2	< 10.5 [10.3] (2.2) nW					
	path 3	< 1.10 [0.93] (0.19) µW	7				
	after external zeroing 5		(): typical at 1 GHz				
	path 1	< 53 [49] (28) pW	(): typical at 1 GHz +15 °C to +35 °C				
	path 2	< 2.2 [2.1] (1.3) nW	110 0 10 700 0				
	path 3	< 224 [192] (108) nW	[]: at frequencies				
Zero drift ⁶	path 1	< 13 [12] (2) pW < 18 GHz					
	path 2	< 0.6 [0.5] (0.1) nW	_ 10 OHZ				
	path 3	< 54 [47] (8) nW	1				
Measurement noise 7	path 1	< 37 [35] (20) pW	1				
	path 2		1				
	path 3	< 1.6 [1.5] (0.9) nW < 158 [136] (76) nW					

Uncertainty for absolute power measurements 8 in dB

	10 MHz to < 20 MHz						
	0.224	0.18	7	0.181			
	0.098	0.08	7	0.085			
	0.058	0.05	3	0.053			
-7	0	-20	–20 0		+23		
Power level in dBm							

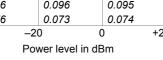
	20 MHz to < 100 MHz						
	0.195		0.177		0.172		0 °C to +50 °C
	0.089		0.085		0.083		+15 °C to +35 °C
	0.055		0.054		0.054		+20 °C to +25 °C
-7	0	-20)	()	+23	
	Power level in dBm						

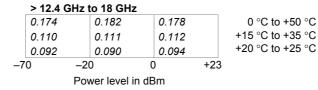
	100 MH	z to 2.4	4 GHz			
	0.161	0	.168		0.163	
	0.084	0	.086		0.085	
	0.060	0	.059		0.060	
-7	0	-20		0)	+23

Power level in dBm					
-20		0	+2		
	0.059	0.060			
	0.086	0.085			

	> 2.4 G	Hz to 8 GHz			
	0.162	0.168	0.164		0 °C to +50 °C
	0.088	0.089	0.088		+15 °C to +35 °C
	0.065	0.063	0.064		+20 °C to +25 °C
-7	0	-20	0	+23	

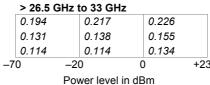
	> 8 GHz to			
	0.166	0.172	0.166	
	0.096	0.096	0.095	
	0.076	0.073	0.074	
-7	0 –2	0	0	+23





Power level in dBm

	> 18 GH	łz to	26.5 GHz	<u> </u>	
	0.178		0.194	0.196	
	0.112		0.117	0.125	
	0.093		0.093	0.105	
-7	0	-2	0	0	+23
Power level in dBm					



ırements ⁹ in dB

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Uncertainty for relative power measur										
	10 MHz to									
+23	0.267	0.239	0.027							
	0.107	0.097	0.026							
+6	0.047	0.041	0.026							
0										
U	0.260	0.028	0.239							
	0.103	0.024	0.097							
-14	0.044	0.023	0.041							
-20										
-20	0.022	0.260	0.267							
	0.022	0.103	0.107							
-70	0.022	0.044	0.047							
	–70 –20	-14 C		+23						
	Po	wer level in dE	3m							
	100 MHz to	o 2.4 GHz								
+23	0.213	0.217	0.027							
	0.093	0.093	0.026							
+6	0.045	0.040	0.026							
.0										
0	0.208	0.028	0.217							
	0.090	0.024	0.093							
-14	0.043	0.023	0.040							
-14	0.010	0.020	0.070							
-20	0.022	0.208	0.213							
	0.022	0.090	0.093							
-70	0.022	0.043	0.045							
	-70 -20	-14 C		+23						
		wer level in dE	3m	-						

ient	s in ab							
	20 MHz to	< 10	0 MHz	:				
+23	0.242	0	.228		0.027		0 °C to +50 °C)
	0.100	0	.096		0.026		+15 °C to +35 °C)
+6	0.045	0	.041		0.026		+20 °C to +25 °C)
0	0.235	0	.028		0.228		0 °C to +50 °C)
	0.097	0	.024		0.096		+15 °C to +35 °C)
-14	0.043	0	.023		0.041		+20 °C to +25 °C)
-20	0.022	0	.235		0.242		0 °C to +50 °C)
	0.022	0	.097		0.100		+15 °C to +35 °C)
-70	0.022	0	.043		0.045		+20 °C to +25 °C)
	-70 -20) –1	4	0 +	- 6	+23		
	Р	ower	level in	dBm				

	100 M	Hz to	2	.4 GHz				
+23	0.213			0.217			0.027	
	0.093			0.093			0.026	
+6	0.045			0.040			0.026	
0	0.208			0.028			0.217	
	0.090			0.024			0.093	
-14	0.043			0.023			0.040	
-2 0	0.022			0.208			0.213	
	0.022			0.090			0.093	
-70	0.022			0.043			0.045	
	– 70	-20		-14		0	+6	+23
		Pov	ve	r level ir	า d	Bm	1	

	> 2.4 GHz	to 8 GHz		
+23	0.211	0.214	0.027	0 °C to +50 °C
	0.095	0.093	0.026	+15 °C to +35 °C
+6	0.050	0.042	0.026	+20 °C to +25 °C
0	0.205	0.028	0.214	0 °C to +50 °C
	0.092	0.024	0.093	+15 °C to +35 °C
-14	0.047	0.023	0.042	+20 °C to +25 °C
-20	0.022	0.205	0.211	0 °C to +50 °C
	0.022	0.092	0.095	+15 °C to +35 °C
-70	0.022	0.047	0.050	+20 °C to +25 °C
	−70 −20	_14 0	+6 +23	
	Po	ower level in d	Bm	

	> 8 GHz 1	o 1	2.4 GHz			
+23	0.212		0.215		0.029	
	0.099		0.097		0.027	
+6	0.056		0.048		0.027	
0	0.207		0.029		0.215	
	0.095		0.025		0.097	
-14	0.052		0.024		0.048	
-20	0.022		0.207		0.212	
	0.022		0.095		0.099	
-70	0.022		0.052		0.056	
	− 70 − 2	0	-14	0	+6	+23
	P	owe	er level in	dB	m	

	> 12.4 GH	z to 18 GHz						
+23	0.219	0.223	0.034	0 °C to +50 °C				
	0.109	0.108	0.033	+15 °C to +35 °C				
+6	0.069	0.064	0.032	+20 °C to +25 °C				
0	0.212	0.031	0.223	0 °C to +50 °C				
	0.102	0.027	0.108	+15 °C to +35 °C				
-14	0.061	0.026	0.064	+20 °C to +25 °C				
-20	0.022	0.212	0.219	0 °C to +50 °C				
	0.022	0.102	0.109	+15 °C to +35 °C				
-70	0.022	0.061	0.069	+20 °C to +25 °C				
	-70 - 20) –14 0	+6 +23					
	Power level in dBm							

	> 18 G	Hz to	26.5 GI	Ηz			
+23	0.242		0.254		0.049		
	0.134		0.139		0.049		
+6	0.098		0.099		0.049		
0	0.231		0.038		0.254		
	0.119		0.034		0.139		
-14	0.079		0.032		0.099		
-20	0.022		0.231		0.242		
	0.022		0.119		0.134		
-70	0.022		0.079		0.098		
	–70	-20	-14	0	+6	+23	
	Power level in dBm						

	> 26.5 GH	z to 33 GHz					
+23	0.268	0.288	0.067	0 °C to +50 °C			
	0.162	0.174	0.067	+15 °C to +35 °C			
+6	0.129	0.136	0.067	+20 °C to +25 °C			
0	0.252	0.047	0.288	0 °C to +50 °C			
	0.137	0.042	0.174	+15 °C to +35 °C			
-14	0.096	0.040	0.136	+20 °C to +25 °C			
-20	0.023	0.252	0.268	0 °C to +50 °C			
	0.023	0.137	0.162	+15 °C to +35 °C			
-70	0.023	0.096	0.129	+20 °C to +25 °C			
	−70 −20	-14 0	+6 +23				
	Power level in dBm						

R&S®NRP40S(N)/50S(N) multipath power sensors

Specifications from 50 MHz to 40 GHz apply to the R&S®NRP40S(N). Specifications from 50 MHz to 50 GHz apply to the R&S®NRP50S(N).

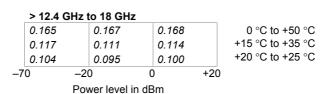
Frequency range	R&S®NRP40S(N)	50 MHz to 40 GHz			
	R&S®NRP50S(N)	50 MHz to 50 GHz			
Impedance matching (SWR)	50 MHz to 2.4 GHz	< 1.13 (1.11)			
	> 2.4 GHz to 8.0 GHz	< 1.20 (1.18)			
	> 8.0 GHz to 18.0 GHz	< 1.25 (1.23)			
	> 18.0 GHz to 26.5 GHz	< 1.30 (1.28)	(): +15 °C to +35 °C		
	> 26.5 GHz to 33.0 GHz	< 1.35 (1.33)			
	> 33.0 GHz to 40.0 GHz	< 1.37 (1.35)			
	> 40.0 GHz to 50.0 GHz	< 1.40 (1.38)			
Power measurement range	continuous average	100 pW to 100 mW (-70	,		
	burst average	300 nW to 100 mW (-35			
	timeslot/gate average	300 pW to 100 mW (-65			
	trace	2 nW to 100 mW (-57 dB			
Max. power	average power	0.2 W (+23 dBm) AVG, m	nax. 10 V DC		
	peak envelope power	1 W (+30 dBm) for max.	10 μs		
Measurement subranges	path 1	-70 dBm to -15 dBm			
	path 2	-53 dBm to +5 dBm			
	path 3	-33 dBm to +20 dBm			
Transition regions	with automatic path selection ³	(-20 ± 1) dBm to (-14 ± 1)	I) dBm		
		(0 ± 1) dBm to $(+6 \pm 1)$ dl	3m		
Dynamic response	video bandwidth	> 100 kHz (150 kHz)	(): +15 °C to +35 °C		
	rise time 10 %/90 %	< 5 µs (3 µs)	(). +13 0 10 +33 0		
Acquisition	sample rate (continuous)	2 Msps			
Triggering	internal				
	threshold level range	-38 dBm to +20 dBm			
	threshold level accuracy	identical to uncertainty fo	r absolute power		
	threshold level hysteresis	0 dB to 10 dB			
	dropout ⁴	0 s to 10 s			
	external	external EXTernal[1]: R&S®NRP2 or R&S®			
		EXTernal2: coaxial trigger I/0			
	slope (external, internal)	pos./neg.			
	delay	−5 s to +10 s			
	hold-off	0 s to 10 s			
	resolution (delay, hold-off, dropout)	0.5 μs (sample period)			
	source	INTernal, EXTernal[1], EX	XTernal2,		
		IMMediate, BUS, HOLD			
Zero offset	initial, without zeroing				
	path 1	< 280 [235] (50) pW			
	path 2	< 26.3 [22.0] (4.8) nW			
	path 3	< 1.34 [1.06] (0.23) µW			
	after external zeroing ⁵		() () () () ()		
	path 1	< 58 [49] (28) pW	(): typical at 1 GHz		
	path 2	< 5.5 [4.6] (2.7) nW	+15 °C to +35 °C		
	path 3	< 280 [220] (130) nW	[]: at fractionsies		
Zero drift ⁶	path 1	[]			
∠GIO UIIIL	path 2	< 14 [12] (2) pW ≤ 18 GHz < 1.3 [1.1] (0.2) nW			
	path 3	< 67 [53] (9) nW	-		
Measurement noise 7	path 1		-		
wicasulellielli 110156	·	< 41 [35] (20) pW < 3.9 [3.3] (1.9) nW			
	path 2				

Uncertainty for absolute power measurements 8 in dB

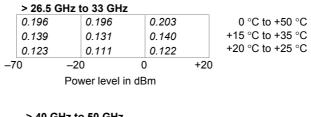
		•			•	
	50 MHz	to <	200 MHz	<u>:</u>		
	0.241		0.196		0.193	
	0.113		0.098		0.099	
	0.077		0.073		0.077	
-7	0	-2	0	()	+20
		Pov	wer level i	n dE	3m	

	200 MF	lz to	8 GHz				
	0.162		0.172		0.171		0 °C to +50 °C
	0.095		0.094		0.097		+15 °C to +35 °C
	0.081		0.074		0.078		+20 °C to +25 °C
-7	0	-20)	()	+20	
Power level in dBm							

> 8	GHz t	o 12.4 GHz				
0.1	152	0.157	0.157			
0.1	103	0.098	0.101			
0.0	090	0.081	0.086			
-70		-20	0	+20		
Power level in dBm						



	> 18 GHz	to 26.5 GHz	<u>.</u>			
	0.176	0.176	0.180			
	0.122	0.114	0.120			
	0.107	0.095	0.103			
-7	0 -	-20	0	+20		
Power level in dBm						



	> 33 GHz to 40 GHz					
	0.216		0.217		0.229	
	0.152		0.145		0.159	
	0.134		0.122		0.138	
-7	0	-2	0	C)	+20
Power level in dBm						

	> 40 GH	z to 50 GHz					
	0.257	0.260	0.279		0 °C to +50 °C		
	0.188	0.184	0.205		+15 °C to +35 °C		
	0.169	0.160	0.183		+20 °C to +25 °C		
-7	0	-20	0	+20			
	Power level in dBm						

Uncertainty for relative power measurements ⁹ in dB

	50 MHz to	<	200 MHz			
+20	0.285		0.252		0.046	
	0.127		0.117		0.045	
+6	0.081		0.077		0.045	
0	0.277		0.040		0.252	
	0.121		0.038		0.117	
-14	0.073		0.038		0.077	
-20	0.028		0.277		0.285	
	0.028		0.121		0.127	
-70	0.028		0.073		0.081	
	−70 −20		-14	0	+6	+20
	Power level in dBm					

. •	· u			
	200 MHz t	o < 8 GHz		
+20	0.214	0.221	0.047	0 °C to +50 °C
	0.109	0.109	0.047	+15 °C to +35 °C
+6	0.083	0.077	0.047	+20 °C to +25 °C
0	0.206	0.040	0.221	0 °C to +50 °C
	0.102	0.038	0.109	+15 °C to +35 °C
-14	0.076	0.038	0.077	+20 °C to +25 °C
-20	0.029	0.206	0.214	0 °C to +50 °C
	0.029	0.102	0.109	+15 °C to +35 °C
-70	0.029	0.076	0.083	+20 °C to +25 °C
	-70 - 20	_14 0	+6 +20	
	Po	ower level in de	3m	

	> 8 GH	dz to	12.4 GHz	<u> </u>		
+20	0.195		0.199		0.050	
	0.111		0.108		0.049	
+6	0.086		0.080		0.049	
0	0.187		0.041		0.199	
	0.104		0.039		0.108	
-14	0.079		0.039		0.080	
-20	0.029		0.187		0.195	
	0.029		0.104		0.111	
-70	0.029		0.079		0.086	
	–70	-20	-14	0	+6	+20
		Pow	er level i	n dBn	ı	

	> 12.4 GH	Iz to 18 GHz						
+20	0.203	0.205	0.054	0 °C to +50 °C				
	0.117	0.113	0.054	+15 °C to +35 °C				
+6	0.092	0.085	0.054	+20 °C to +25 °C				
-								
0	0.194	0.043	0.205	0 °C to +50 °C				
	0.109	0.041	0.113	+15 °C to +35 °C				
-14	0.083	0.041	0.085	+20 °C to +25 °C				
-20	0.030	0.194	0.203	0 °C to +50 °C				
	0.030	0.109	0.117	+15 °C to +35 °C				
-70	0.030	0.083	0.092	+20 °C to +25 °C				
	_70 <u>_2</u> 0	0 –14 0	+6 +20					
	Power level in dBm							

	> 18 G	Hz to	26.5 GH	z		
+20	0.226		0.227		0.064	
	0.134		0.130		0.064	
+6	0.106		0.099		0.064	
0	0.214		0.048		0.227	
	0.122		0.046		0.130	
-14	0.092		0.046		0.099	
-20	0.032		0.214		0.226	
	0.032		0.122		0.134	
-70	0.032		0.092		0.106	
	–70	-20	-14	0	+6	+20
Power level in dBm						

	> 26.5 GH	z to 33 GHz					
+20	0.252	0.254	0.074	0 °C to +50 °C			
	0.153	0.151	0.074	+15 °C to +35 °C			
+6	0.122	0.117	0.074	+20 °C to +25 °C			
0	0.236	0.054	0.254	0 °C to +50 °C			
	0.135	0.052	0.151	+15 °C to +35 °C			
-14	0.101	0.051	0.117	+20 °C to +25 °C			
-20	0.034	0.236	0.252	0 °C to +50 °C			
	0.034	0.135	0.153	+15 °C to +35 °C			
-70	0.034	0.101	0.122	+20 °C to +25 °C			
-70 -20 -14 0 +6 +20							
Power level in dBm							

	> 33 G	Hz to	40 GHz				
+20	0.285		0.289		0.088		
	0.176		0.179		0.087		
+6	0.141		0.142		0.087		
-							
0	0.263		0.062		0.289		
	0.151		0.060		0.179		
-14	0.111		0.059		0.142		
-20	0.036		0.263		0.285		
	0.036		0.151		0.176		
-70	0.036		0.111		0.141		
	– 70	-20	-14	0	+6	+20	
	Power level in dBm						

	> 40 GHz t	o 50 GHz				
+20	0.336	0.344	0.110	0 °C to +50 °C		
	0.214	0.224	0.110	+15 °C to +35 °C		
+6	0.174	0.184	0.109	+20 °C to +25 °C		
0	0.304	0.077	0.344	0 °C to +50 °C		
	0.174	0.074	0.224	+15 °C to +35 °C		
-14	0.126	0.073	0.184	+20 °C to +25 °C		
-20	0.040	0.304	0.336	0 °C to +50 °C		
	0.040	0.174	0.214	+15 °C to +35 °C		
-70	0.040	0.126	0.174	+20 °C to +25 °C		
	−70 −20	-14 0	+6 +20			
Power level in dBm						

Additional characteristics of the R&S®NRPxxS(N) multipath power sensors and the R&S®NRP33SN-V multipath power sensor for use in thermal vacuum

Sensor type		three-path diode power sensor
Measurand		power of incident wave
		power of source (DUT) into 50 Ω ¹⁰
RF connector	R&S®NRP8S(N)/18S(N)	N (male)
	R&S®NRP33S(N)/33SN-V	3.5 mm (male)
	R&S®NRP40S(N)	2.92 mm (male)
	R&S®NRP50S(N)	2.4 mm (male)
Measurement functions	stationary and recurring waveforms	continuous average
	and the second s	burst average
		timeslot/gate average
		trace
	single events	burst average
	omgre evente	timeslot/gate average
		trace
Continuous average function	measurand	mean power over recurring acquisition interval
Continuous average function	aperture	10 μs to 2.0 s (20 ms default)
	window function	uniform or von Hann 11
	duty cycle correction ¹²	0.001 % to 100.0 %
	capacity of measurement buffer ¹³	1 to 8192 results
Burst average function	measurand	mean power over burst portion of recurring signal
Buist average function	measurand	(trigger settings required)
	detectable burst width 14	5 us to 8 s
	minimum gap between bursts	5 µs
	dropout period ¹⁵ for burst end	·
	detection	1 µs to 300 ms
	exclusion periods ¹⁶	
		0 s to 1 s
	start end	0 s to 1 s
	resolution (dropout and exclusion periods)	0.5 μs (sample period)
Timeslot/gate average function	measurand	mean power over individual timeslots/gates
	number of timeslots/gates	1 to 32 (consecutive)
	nominal length	10 μs to 0.1 s
	start of first timeslot/gate	at delayed trigger event
	exclusion periods	
	start	0 s to 1 s
	end	0 s to 1 s
	resolution (nominal length and	0.5 µs (sample period)
	exclusion periods)	
Trace function	measurand	mean, random, maximum and minimum power
		over pixel length
	acquisition	
	length	10 μs to 3.0 s
	start (referenced to delayed trigger)	-3.0 s to 3.0 s
	result	
	pixels	1 to 8192
	resolution	≥ 0.5 µs (sample period)

Averaging filter	modes	auto off (fixed averaging number)
		auto on (continuously auto-adapted)
		auto once (automatically fixed once)
	auto off	
	supported measurement functions	all
	averaging number	1, 2, 4, 6, 8, 10 to 65536 (1 or all even numbers between 2 and 65536)
	auto on/once	
	supported measurement functions	continuous average, burst average, timeslot/gate average
	normal operating mode	averaging number adapted to resolution setting and power to be measured
	fixed noise operating mode	averaging number adapted to specified noise content
	result output	
	moving mode	continuous result output, independent of averaging number
	repeat mode	only final result
Attenuation correction	function	corrects the measurement result by means of a fixed factor (dB offset)
	range	-200.000 dB to +200.000 dB
Embedding	function	incorporates a two-port device at the
v		sensor input so that the measurement plane is shifted to the input of this device
	parameters	S_{11} , S_{21} , S_{12} and S_{22} of device
	number of devices	0 to 999
	total number of frequencies	< 80000
Gamma correction	function	removes the influence of impedance
Gainna correction	Tunction	mismatch from the measurement result so that the measurand corresponds to the power of the source (DUT) into 50 Ω
	parameters	magnitude and phase of reflection coefficient of source (DUT)
Frequency response correction	function	takes the frequency response of the sensor section and of the RF power attenuator into account (if applicable)
	parameter	center frequency of test signal
	residual uncertainty	see specification of calibration uncertainty and uncertainty for absolute and relative
Measurement times 17	continuous average	power measurements
Av: averaging number	continuous average single measurements	2 x (aperture ± 100 us) x Ay ± 4
Av. averaging number	buffered measurements	$2 \times (aperture + 100 \ \mu s) \times Av + t_z$
Zanain m (drimati)	without averaging	$2 \times (aperture + 116 \mu s) \times buffer size + t_z$ $t_z = 2 ms (typ.)$
Zeroing (duration)		5.3 s
Measurement error due to modulation ¹⁸	general	depends on CCDF and RF bandwidth of test signal
	WCDMA (3GPP test model 1-64)	
	worst case	-0.02 dB to +0.05 dB
	typical	-0.01 dB to +0.03 dB
	E-UTRA test model 1.1 (E-TM1.1), 20 MH	
	worst case	-0.03 dB to +0.08 dB
	typical	-0.02 dB to +0.05 dB
Change of input reflection coefficient	R&S®NRP8S(N)/18S(N)/33S(N)/33SN-V	
with respect to power 19	10 MHz to 2.4 GHz	< 0.02 (0.01) (): +15 °C to +35 °C
	> 2.4 GHz	< 0.03 (0.02)
	R&S®NRP40S(N)/50S(N)	·
	50 MHz to 8.0 GHz	< 0.04 (0.02)
	> 8.0 GHz to 18.0 GHz	< 0.06 (0.03)
		< 0.07 (0.04) (): levels ≤ 10 dBm
	> 18.0 GHz to 33.0 GHz	< 0.07 (0.04)

Version 03.00, February 2016

Calibration uncertainty 20	R&S®NRP8S(N)/18S(N)/33S(N)/ 33SN-V	path 1	path 2	path 3
	10 MHz to < 100 MHz	0.058 dB	0.052 dB	0.053 dB
	100 MHz to 2.40 GHz	0.060 dB	0.058 dB	0.058 dB
	> 2.4 GHz to 8.0 GHz	0.065 dB	0.062 dB	0.063 dB
	> 8.0 GHz to 12.4 GHz	0.075 dB	0.071 dB	0.072 dB
	> 12.4 GHz to 18.0 GHz	0.092 dB	0.088 dB	0.089 dB
	> 18.0 GHz to 26.5 GHz	0.093 dB	0.089 dB	0.090 dB
	> 26.5 GHz to 33.0 GHz	0.113 dB	0.108 dB	0.109 dB
	R&S®NRP40S(N)/50S(N)	path 1	path 2	path 3
	50 MHz to < 200 MHz	0.076 dB	0.070 dB	0.071 dB
	200 MHz to 8.0 GHz	0.080 dB	0.070 dB	0.077 dB
	> 8.0 GHz to 12.4 GHz	0.089 dB	0.077 dB	0.072 dB
	> 12.4 GHz to 18.0 GHz	0.104 dB	0.079 dB	0.094 dB
	> 18.0 GHz to 26.5 GHz	0.107 dB	0.092 dB	0.093 dB
	> 26.5 GHz to 33.0 GHz	0.123 dB	0.107 dB	0.108 dB
	> 33.0 GHz to 40.0 GHz	0.133 dB	0.115 dB	0.117 dB
	> 40.0 GHz to 50.0 GHz	0.168 dB	0.150 dB	0.152 dB
Host interface	mechanical		2 connector (A-c	
	power supply		B high-power de	
	speed	according to th	speed and full-sp	beed modes
	remote control protocols		test and measur	oment device
	remote control protocols		C) and legacy m	
				x power sensors
	trigger input EXTernal[1]	differential (0 V		x power sensors
	reference clock	unierentiai (0 v	7+3.5 V)	
	signal level	LVDS		
	frequency	20 MHz		
	permissible total cable length	≤ 5 m		
Ethernet interface	mechanical	RJ-45 jack		
only for R&S®NRPxxSN types and	power supply		ernet (PoE) clas	ss 1 device
the R&S®NRP33SN-V	speed	10/100/1000 M		30 1 device
	remote control protocols		(high-speed LAI	N instrument
	remete seria er proteseie		I-RAW (port 502	
	permissible cable length	≤ 100 m	(J	- /
Trigger-I/O EXTernal2	mechanical	SMB built-in jac	ck	
	impedance		-	
	input	10 kΩ or 50 Ω		
	output	50 Ω		
	signal level			
	input	compatible with	n 3 V or 5 V logic	c, max. –1 to +6 V
	output	≥ 2 V into 50 Ω	load, max. 5.3	V
Vacuum-specific characteristics	recommended	vacuum bake f	or 100 h at +85 °	°C and
of the R&S®NRP33SN-V	bake-out procedure	P < 10 ⁻⁵ mbar		
	typical mass loss during bake-out	70 mg		
Mounting of R&S®NRP33SN-V	general data		hrough-holes ar	
onto a baseplate		mounting the s	ensor to a baser	olate.
for technical drawings see Appendix		Using a low-ou	tgassing therma	l interface materia
			te foil is highly re	ecommended.
	distance between mounting holes	2" (50.8 mm)		
	thread standard	UNC 8-32		
	thread length	½ " (6.35 mm)		
Dimensions (W × H × L)	R&S®NRPxxS	48 mm × 30 mi	m × 138 mm	
		(1.89 in × 1.18		
	R&S®NRPxxSN, R&S®NRP33SN-V	73 mm × 26 mi		
		(2.87 in × 1.02		
Weight	R&S®NRPxxS	< 0.20 kg (0.44		
	R&S®NRPxxSN, R&S®NRP33SN-V	< 0.35 kg (0.77	lh)	

Thermal power sensors

R&S®NRP18T(N)/33T(N)/40T(N)/50T(N)/67T(N) thermal power sensors

Specifications from DC to 18 GHz apply to the R&S®NRP18T(N). Specifications from DC to 33 GHz apply to the R&S®NRP33T(N). Specifications from DC to 40 GHz apply to the R&S®NRP40T(N). Specifications from DC to 50 GHz apply to the R&S®NRP50T(N). Specifications from DC to 67 GHz apply to the R&S®NRP67T(N).

Frequency range	R&S®NRP18T(N)	DC to 18 GHz	<u> </u>			
	R&S®NRP33T(N)	DC to 33 GHz	7			
	R&S®NRP40T(N)	DC to 40 GHz	7			
	R&S®NRP50T(N)	DC to 50 GHz	7			
	R&S®NRP67T(N)	DC to 67 GHz	<u>z</u>			
mpedance matching (SWR)	DC to 100 MHz	< 1.03				
	> 100 MHz to 2.4 GHz	< 1.06				
	> 2.4 GHz to 12.4 GHz	< 1.13				
	> 12.4 GHz to 18.0 GHz	< 1.16				
	> 18.0 GHz to 26.5 GHz	< 1.22				
	> 26.5 GHz to 33.0 GHz	< 1.28				
	> 33.0 GHz to 40.0 GHz	< 1.28				
	> 40.0 GHz to 44.0 GHz	< 1.30				
	> 44.0 GHz to 50.0 GHz	< 1.30				
	> 50.0 GHz to 67.0 GHz	< 1.35				
Power measurement range		300 nW to 10	0 mW (-35 dBm t	o +20 dBm),		
		continuous, ir	n a single range			
lax. power	average power	0.3 W (+25 d	0.3 W (+25 dBm), continuous			
	peak envelope power					
	R&S®NRP18T(N)		n) for max. 1 µs			
	R&S®NRP33T(N)/40T(N)/	10 W (40 dBr	n) for max. 1 µs			
	50T(N)/67T(N)					
cquisition	sample rate	20.833 kHz (sigma-delta)				
ero offset	after external zeroing 5	< 25 nW (typ. 15 nW at 1 GHz)				
ero drift ⁶		< 8 nW				
leasurement noise ⁷			15 nW at 1 GHz)			
Incertainty for absolute power		+20 °C to	+15 °C to	0 °C to		
neasurements ²¹		+25 °C	+35 °C	+50 °C		
	DC to 100 MHz	0.040 dB	0.046 dB	0.067 dB		
	> 100 MHz to 2.4 GHz	0.048 dB	0.053 dB	0.072 dB		
	> 2.4 GHz to 8.0 GHz	0.054 dB	0.059 dB	0.079 dB		
	> 8.0 GHz to 12.4 GHz	0.063 dB	0.068 dB	0.085 dB		
	> 12.4 GHz to 18.0 GHz	0.082 dB	0.086 dB	0.100 dB		
	> 18.0 GHz to 26.5 GHz	0.086 dB	0.086 dB	0.102 dB		
	> 26.5 GHz to 33.0 GHz	0.101 dB	0.105 dB	0.121 dB		
	> 33.0 GHz to 40.0 GHz	0.108 dB	0.112 dB	0.127 dB		
	> 40.0 GHz to 44.0 GHz	0.138 dB	0.141 dB	0.155 dB		
	> 44.0 GHz to 50.0 GHz	0.143 dB	0.146 dB	0.159 dB		
	> 50.0 GHz to 59.0 GHz	0.206 dB	0.208 dB	0.220 dB		
	> 59.0 GHz to 67.0 GHz	0.248 dB	0.250 dB	0.260 dB		
Incertainty for relative power		0.010 dB				
neasurements 22						

R&S®NRP110T thermal power sensor

Frequency range		DC to 110 GH	z			
Impedance matching (SWR)	DC to 100 MHz	< 1.05				
	> 100 MHz to 2.4 GHz	< 1.08				
	> 2.4 GHz to 12.4 GHz	< 1.18				
	> 12.4 GHz to 18.0 GHz	< 1.23	< 1.23			
	> 18.0 GHz to 26.5 GHz	< 1.28				
	> 26.5 GHz to 40.0 GHz	< 1.38				
	> 40.0 GHz to 50.0 GHz	< 1.46	< 1.46			
	> 50.0 GHz to 67.0 GHz	< 1.56				
	> 67.0 GHz to 80.0 GHz	< 1.60				
	> 80.0 GHz to 95.0 GHz	< 1.66				
	> 95.0 GHz to 110.0 GHz	< 1.70				
Power measurement range		300 nW to 10	00 nW to 100 mW (-35 dBm to +20 dBm),			
J		continuous, in	continuous, in a single range			
Max. power	average power	0.3 W (+25 dE	W (+25 dBm), continuous			
•	peak envelope power	10 W (40 dBn	n) for max. 1 µs			
Acquisition	sample rate	20.833 kHz (s	igma-delta)			
Zero offset	after external zeroing 5	< 34 nW (typ.	15 nW at 1 GHz)			
Zero drift ⁶		< 11 nW	< 11 nW			
Measurement noise ⁷		< 34 nW (typ.	< 34 nW (typ. 15 nW at 1 GHz)			
Uncertainty for absolute power		+20 °C to	+15 °C to	0 °C to		
measurements ²¹		+25 °C	+35 °C	+50 °C		
	DC to 100 MHz	0.041 dB	0.047 dB	0.068 dB		
	> 100 MHz to 2.4 GHz	0.051 dB	0.057 dB	0.074 dB		
	> 2.4 GHz to 12.4 GHz	0.074 dB	0.078 dB	0.093 dB		
	> 12.4 GHz to 18.0 GHz	0.098 dB	0.101 dB	0.113 dB		
	> 18.0 GHz to 26.5 GHz	0.099 dB	0.103 dB	0.115 dB		
	> 26.5 GHz to 40.0 GHz	0.118 dB	0.122 dB	0.135 dB		
	> 40.0 GHz to 50.0 GHz	0.166 dB	0.169 dB	0.182 dB		
	> 50.0 GHz to 59.0 GHz	0.226 dB	0.229 dB	0.244 dB		
	> 59.0 GHz to 67.0 GHz	0.265 dB	0.268 dB	0.280 dB		
	> 67.0 GHz to 80.0 GHz	0.283 dB	0.286 dB	0.299 dB		
	> 80.0 GHz to 95.0 GHz	0.298 dB	0.302 dB	0.317 dB		
	> 95.0 GHz to 110.0 GHz	0.318 dB	0.321 dB	0.337 dB		
Uncertainty for relative power	DC to 67.0 GHz	0.010 dB	1	1		
measurements 22	> 67.0 GHz to 110.0 GHz	0.014 dB				

Additional characteristics of the R&S $^{\otimes}$ NRP18T(N)/33T(N)/40T(N)/50T(N)/67T(N)/110T thermal power sensors

Sensor type		thermoelectric power sensor
Measurand		power of incident wave
		power of source (DUT) into 50 Ω ¹⁰
RF connector	R&S®NRP18T(N)	N (male)
	R&S®NRP33T(N)	3.50 mm (male)
	R&S®NRP40T(N)	2.92 mm (male)
	R&S®NRP50T(N)	2.40 mm (male)
	R&S®NRP67T(N)	1.85 mm (male)
	R&S®NRP110T	1.00 mm (male)
Measurement function	stationary and recurring waveforms	continuous average
Continuous average function	measurand	mean power over recurring acquisition interval
Continuous average function		0.5 ms to 300 ms (5 ms default)
	aperture window function	uniform or von Hann ¹¹
	duty cycle correction 12	0.001 % to 100.0 %
	capacity of measurement buffer 13	1 to 8192 results
Averaging filter	modes	auto off (fixed averaging number)
		auto on (continuously auto-adapted)
		auto once (automatically fixed once)
	auto off	
	averaging number	1, 2, 4, 6, 8, 10 to 65536 (1 or all even numbers
		between 2 and 65536)
	auto on/once	
	normal operating mode	averaging number adapted to resolution setting and power to be measured
	fixed noise operating mode	averaging number adapted to specified noise content
	result output	Contont
	moving mode	continuous result output, independent of
	moving mode	averaging number
	repeat mode	only final result
Attenuation correction	function	corrects the measurement result by means of a
Attenuation correction	Turiction	fixed factor (dB offset)
	rongo	-200.000 dB to +200.000 dB
Embadding.	range	incorporates a two-port device at the sensor input
Embedding	function	so that the measurement plane is shifted to the input of this device
	parameters	S_{11} , S_{21} , S_{12} and S_{22} of device
	frequencies	0 to 999
Gamma correction	function	removes the influence of impedance mismatch
Gaillilla correction	Tunction	from the measurement result so that the power of
		the source (DUT) into 50 Ω can be read
	parameters	magnitude and phase of reflection coefficient of source (DUT)
Frequency response correction	function	takes the frequency response of the power sensor into account
	parameter	center frequency of test signal
	residual uncertainty	see specification of calibration uncertainty and uncertainty for absolute and relative power measurements
Measurement time ¹⁷	continuous average	$2 \times (aperture + 150 \ \mu s) \times Av + t_z + t_d$
Av: averaging number	single measurements	$2 \times (aperture + 150 \ \mu s) \times AV + l_z + l_d$ $t_z := 4 \ ms (typ.)$
Averaging number	onigie measurements	t_2 : - 4 ms (typ.) t_3 must be taken into account when auto delay is
		,
	dolay timo t	active
	delay time t_d	00
	R&S®NRP18T(N)/	80 ms
	R&S®NRP33T(N)/40T(N)/50T(N)/ 67T(N)/110T	40 ms
Zeroing (duration)	- (,	10 s
Change of input reflection co-	only for power levels > 15 dBm	< 0.005
	5, 101 pottor 101010 - 10 dbill	0.000

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Calibration uncertainty ²³	R&S®NRP18T(N)/33T(N)/40T(N)/50	DT(N)/ 67T(N)
,	DC to 100 MHz	0.040 dB
	> 100 MHz to 2.4 GHz	0.047 dB
	> 2.4 GHz to 8.0 GHz	0.054 dB
	> 8.0 GHz to 12.4 GHz	0.063 dB
	> 12.4 GHz to 18.0 GHz	0.082 dB
	> 18.0 GHz to 26.5 GHz	0.085 dB
	> 26.5 GHz to 33.0 GHz	0.101 dB
	> 33.0 GHz to 40.0 GHz	0.108 dB
	> 40.0 GHz to 44.0 GHz	0.138 dB
	> 44.0 GHz to 50.0 GHz	0.143 dB
	> 50.0 GHz to 59.0 GHz	0.190 dB
	> 59.0 GHz to 67.0 GHz	0.235 dB
	R&S®NRP110T	
	DC to 100 MHz	0.041 dB
	> 100 MHz to 2.4 GHz	0.051 dB
	> 2.4 GHz to 12.4 GHz	0.074 dB
	> 12.4 GHz to 18.0 GHz	0.098 dB
	> 18.0 GHz to 26.5 GHz	0.099 dB
	> 26.5 GHz to 40.0 GHz	0.118 dB
	> 40.0 GHz to 50.0 GHz	0.166 dB
	> 50.0 GHz to 59.0 GHz	0.211 dB
	> 59.0 GHz to 67.0 GHz	0.253 dB
	> 67.0 GHz to 80.0 GHz	0.256 dB
	> 80.0 GHz to 95.0 GHz	0.273 dB
	> 95.0 GHz to 110.0 GHz	0.294 dB
Temperature effect ²⁴	DC to 100 MHz	< 0.002 dB/K
remperature effect	> 100 MHz to 50.0 GHz	< 0.002 dB/K
1 1 25	> 50.0 GHz to 110.0 GHz	< 0.006 dB/K
Linearity ²⁵	DC to 67.0 GHz	0.007 dB
	> 67.0 GHz to 110.0 GHz	0.010 dB
Host interface	mechanical	8-pin male M12 connector (A-coded)
	power supply	+5 V/0.5 A (USB high-power device)
	speed	supports high-speed and full-speed modes
		according to the specification
	remote control protocols	supports USB test and measurement device
		class (USBTMC) and legacy mode for
		compatibility with R&S®NRP-Zxx power sensors
	trigger input EXTernal[1]	differential (0 V/+3.3 V)
	reference clock	
	signal level	LVDS
	frequency	20 MHz
	permissible total cable length	≤ 5 m
Ethernet interface	mechanical	RJ-45 jack
only for R&S®NRPxxTN types	power supply	power over Ethernet (PoE) class 1 device
31.32	speed	10/100/1000 Mbit/s
	remote control protocols	VXI11, HiSLIP (high-speed LAN instrument
	Single control protocolo	protocol), SCPI-RAW (port 5025)
	permissible cable length	≤ 100 m
Trigger-I/O EXTernal2	mechanical	SMB built-in jack
11199e1-10 EVIEIIIQIS	impedance	OIVID DUILE-III JACK
	input	10 kO or 50 O
	11.01.01.01	10 kΩ or 50 Ω
	-	50.0
	output	50 Ω
	output signal level	
	output	compatible with 3 V or 5 V logic,
	output signal level input	compatible with 3 V or 5 V logic, max. –1 V to +6 V
	output signal level input output	compatible with 3 V or 5 V logic, max. -1 V to +6 V \geq 2 V into 50 Ω load, max. 5.3 V
Dimensions (W × H × L)	output signal level input	compatible with 3 V or 5 V logic, max. -1 V to +6 V \geq 2 V into 50 Ω load, max. 5.3 V 48 mm × 30 mm × 138 mm
Dimensions (W × H × L)	output signal level input output R&S®NRPxxT	compatible with 3 V or 5 V logic, max. -1 V to +6 V \geq 2 V into 50 Ω load, max. 5.3 V 48 mm × 30 mm × 138 mm (1.89 in × 1.18 in × 5.43 in)
Dimensions (W × H × L)	output signal level input output	compatible with 3 V or 5 V logic, max. -1 V to +6 V \geq 2 V into 50 Ω load, max. 5.3 V 48 mm × 30 mm × 138 mm
Dimensions (W × H × L)	output signal level input output R&S®NRPxxT	compatible with 3 V or 5 V logic, max. -1 V to +6 V \geq 2 V into 50 Ω load, max. 5.3 V 48 mm × 30 mm × 138 mm (1.89 in × 1.18 in × 5.43 in)
Dimensions (W × H × L) Weight	output signal level input output R&S®NRPxxT	compatible with 3 V or 5 V logic, max. -1 V to +6 V \geq 2 V into 50 Ω load, max. 5.3 V 48 mm × 30 mm × 138 mm (1.89 in × 1.18 in × 5.43 in) 73 mm × 26 mm × 146 mm

Average power sensors

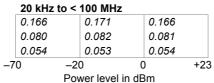
R&S®NRP6A(N)/18A(N) average power sensors

Specifications from 8 kHz to 6 GHz apply to the R&S®NRP6A(N). Specifications from 8 kHz to 18 GHz apply to the R&S®NRP18A(N).

Frequency range	R&S®NRP6A(N)	8 kHz to 6 GHz		
	R&S®NRP18A(N)	8 kHz to 18 GHz		
Impedance matching (SWR)	8 kHz to < 20 kHz	< 1.25 (1.23)		
	20 kHz to 2.4 GHz	< 1.13 (1.11)	(): +15 °C to +35 °C	
	> 2.4 GHz to 8.0 GHz	< 1.20 (1.18)	(). +15 C 10 +35 C	
	> 8.0 GHz to 18.0 GHz	< 1.25 (1.23)		
Power measurement range		100 pW to 200 mW (-70 dBm to +23 dBm)		
Max. power	average power	1 W (+30 dBm) AVG, max. 10 V DC		
	peak envelope power	2 W (+33 dBm) for max. 10 μs		
Measurement subranges	path 1	-70 dBm to -15 dBm		
	path 2	-53 dBm to +5 dBm		
	path 3	-33 dBm to +23 dBm		
Transition regions	with automatic path selection ³	(-20 ± 1) dBm to (-14 ± 1)) dBm	
		(0 ± 1) dBm to $(+6 \pm 1)$ dB	m	
Dynamic response	rise time 10 %/90 %	< 5 ms		
Acquisition	sample rate (continuous)	2 Msps		
Zero offset	initial, without zeroing			
	path 1	< 235 (50) pW		
	path 2	< 10.3 (2.2) nW	=	
	path 3	< 0.93 (0.19) µW		
	after external zeroing ⁵		-	
	path 1	< 49 (28) pW	1	
	path 2	< 2.1 (1.3) nW	(): typical at 1 GHz	
	path 3	< 192 (108) nW	+15 °C to +35 °C	
Zero drift ⁶	path 1	< 12 (2) pW		
	path 2	< 0.5 (0.1) nW		
	path 3	< 47 (8) nW		
Measurement noise 7	path 1	< 35 (20) pW		
	path 2	< 1.5 (0.9) nW		
	path 3	< 136 (76) nW		
	1 1	1 /	1	

Uncertainty for absolute power measurements 8 in dB

8 kHz to < 20 kHz 0.238 0.229 0.223 0.093 0.093 0.089 0.052 0.051 0.052 -70 -20 +23 Power level in dBm





	100 MH	z to	2.4 GHz			
	0.161		0.168		0.163	
	0.081		0.083		0.082	
	0.054		0.054		0.054	
– 70		-2	0	C)	+23
		Pov	wer level	in dE	3m	

	> 2.4 GH	lz to	8 GHz			
	0.158		0.165		0.160	
	0.082		0.083		0.081	
	0.056		0.055		0.055	
– 70		-2)	C)	+23
		Pov	ver level	in dE	3m	

0 °C to +50 °C +15 °C to +35 °C +20 °C to +25 °C

0 °C to +50 °C +15 °C to +35 °C +20 °C to +25 °C

> 8 GHz	> 8 GHz to 12.4 GHz				
0.166	0.172	0.166			
0.096	0.096	0.095			
0.076	0.073	0.074			
-7 0	-20	0	+23		

Power level in dBm

0.174	0.182	0.178	
0.110	0.111	0.112	
0.092	0.090	0.094	
– 70	-20	0	+23

Power level in dBm

Uncertainty for relative power measurements 9 in dB

	8 kHz to <	20) kHz			
+23	0.299		0.292		0.027	
	0.107		0.105		0.026	
+6	0.046		0.041		0.026	
0	0.293		0.029		0.292	
	0.104		0.024		0.105	
-14	0.044		0.023		0.041	
-20	0.022		0.293		0.299	
	0.022		0.104		0.107	
-70	0.022		0.044		0.046	
	−70 −20		-14	0	+6	+23
	Po	we	er level in	dBm		

3 III UD			
20 kHz to	< 100 MHz		
0.220	0.222	0.027	0 °C to +50 °C
0.094	0.093	0.026	+15 °C to +35 °C
0.044	0.040	0.026	+20 °C to +25 °C
0.214	0.028	0.222	0 °C to +50 °C
0.091	0.024	0.093	+15 °C to +35 °C
0.042	0.023	0.040	+20 °C to +25 °C
0.022	0.214	0.220	0 °C to +50 °C
0.022	0.091	0.094	+15 °C to +35 °C
0.022	0.042	0.044	+20 °C to +25 °C
−70 −20) –14 0	+6 +23	
Po	ower level in di	3m	
	20 kHz to 0.220 0.094 0.044 0.214 0.091 0.042 0.022 0.022 0.022 -70 -20	20 kHz to < 100 MHz 0.220	20 kHz to < 100 MHz

	100 MHz t	0 2	2.4 GHz			
+23	0.213		0.217		0.027	
	0.093		0.093		0.026	
+6	0.045		0.040		0.026	
0	0.208		0.028		0.217	
	0.090		0.024		0.093	
-14	0.043		0.023		0.040	
-2 0	0.022		0.208		0.213	
	0.022		0.090		0.093	
-70	0.022		0.043		0.045	
	−70 −20)	-14	0	+6	+23
	Power level in dBm					

	> 2.4 GHz	to 8 GHz		
+23	0.211	0.214	0.027	0 °C to +50 °C
	0.095	0.093	0.026	+15 °C to +35 °C
+6	0.050	0.042	0.026	+20 °C to +25 °C
0	0.205	0.028	0.214	0 °C to +50 °C
	0.092	0.024	0.093	+15 °C to +35 °C
-14	0.047	0.023	0.042	+20 °C to +25 °C
-20	0.022	0.205	0.211	0 °C to +50 °C
	0.022	0.092	0.095	+15 °C to +35 °C
-70	0.022	0.047	0.050	+20 °C to +25 °C
	-70 -20	-14 0	+6 +23	
	Po	wer level in di	Bm	

	> 8 GI	Iz to 1	12.4 GHz			
+23	0.212		0.215		0.029	
	0.099		0.097		0.027	
+6	0.056		0.048		0.027	
0	0.207		0.029		0.215	
	0.095		0.025		0.097	
-14	0.052		0.024		0.048	
-20	0.022		0.207		0.212	
	0.022		0.095		0.099	
-70	0.022		0.052		0.056	
	- 70	-20	-14	0	+6	+23
	Power level in dBm					

	> 12.4 G	Hz to	18 GHz				
+23	0.219		0.223		0.034		0 °C to +50 °C
	0.109		0.108		0.033		+15 °C to +35 °C
+6	0.069		0.064		0.032		+20 °C to +25 °C
0	0.212		0.031		0.223		0 °C to +50 °C
	0.102		0.027		0.108		+15 °C to +35 °C
-14	0.061		0.026		0.064		+20 °C to +25 °C
-20	0.022		0.212		0.219		0 °C to +50 °C
	0.022		0.102		0.109		+15 °C to +35 °C
-70	0.022		0.061		0.069		+20 °C to +25 °C
	– 70 –	·20 ·	-14	0 -	+6	+23	
		Powe	er level in	dBm	1		

Additional characteristics of the R&S®NRPxxA(N) average power sensors

	`	<u> </u>
Sensor type		three-path diode power sensor
Measurand		power of incident wave
		power of source (DUT) into 50 Ω ¹⁰
RF connector		N (male)
Measurement functions	stationary and recurring waveforms	continuous average
Continuous average function	measurand	mean power over recurring acquisition
		interval
	aperture	10 μs to 2.0 s (20 ms default)
	window function	uniform or von Hann 11
	duty cycle correction 12	0.001 % to 100.0 %
	capacity of measurement buffer 13	1 to 8192 results
Averaging filter	modes	auto off (fixed averaging number)
		auto on (continuously auto-adapted)
		auto once (automatically fixed once)
	auto off	
	supported measurement functions	all
	averaging number	1, 2, 4, 6, 8, 10 to 65536 (1 or all even
		numbers between 2 and 65536)
	auto on/once	
	normal operating mode	averaging number adapted to resolution
		setting and power to be measured
	fixed noise operating mode	averaging number adapted to specified
		noise content
	result output	
	moving mode	continuous result output, independent of
		averaging number
	repeat mode	only final result
Attenuation correction	function	corrects the measurement result by
		means of a fixed factor (dB offset)
	range	-200.000 dB to +200.000 dB
Embedding	function	incorporates a two-port device at the
•		sensor input so that the measurement
		plane is shifted to the input of this device
	parameters	S_{11} , S_{21} , S_{12} and S_{22} of device
	number of devices	0 to 999
	total number of frequencies	≤ 80000
Gamma correction	function	removes the influence of impedance
		mismatch from the measurement result
		so that the measurand corresponds to the
		power of the source (DUT) into 50 Ω
	parameters	magnitude and phase of reflection
		coefficient of source (DUT)
Frequency response correction	function	takes the frequency response of the
		sensor section and of the RF power
		attenuator into account (if applicable)
	parameter	center frequency of test signal
	residual uncertainty	see specification of calibration uncertainty
		and uncertainty for absolute and relative
		power measurements
Measurement time ¹⁷	continuous average	
Av: averaging number	single measurements	2 × (aperture + 5 ms) × Av –5 ms + tz
		$t_z = 2 \text{ ms (typ.)}$
Zeroing (duration)		6.6 s
Measurement error due to	general	depends on CCDF and RF bandwidth of
modulation 18		test signal
	WCDMA (3GPP test model 1 to 64)	
	worst case	-0.02 dB to +0.05 dB
	worst case	
	typical	-0.01 dB to +0.03 dB
		-0.01 dB to +0.03 dB
	typical	-0.01 dB to +0.03 dB

Change of input reflection co-	8 kHz to 2.4 GHz	< 0.02 (0.01)		/ \	00 t05 00	
efficient with respect to power 19	> 2.4 GHz	< 0.03 (0.02)		(): +15	°C to +35 °C	
Calibration uncertainty 20		path 1	path 2 path 3			
-	8 kHz to < 20 kHz	0.052 dB	0.05	0 dB	0.050 dB	
	20 kHz to < 100 MHz	0.055 dB	0.055 dB 0.052 dB 0		0.053 dB	
	100 MHz to 2.40 GHz	0.054 dB	0.054 dB 0.052 dB 0		0.053 dB	
	> 2.4 GHz to 8.0 GHz	0.056 dB	0.05	3 dB	0.053 dB	
	> 8.0 GHz to 12.4 GHz	0.065 dB	0.062 dB		0.062 dB	
	> 12.4 GHz to 18.0 GHz	0.076 dB	0.07	3 dB	0.075 dB	
Host interface	mechanical	8-pin male M12	conne	ctor (A-co	ded)	
	power supply	+5 V/0.5 A (US				
	speed	supports high-s according to th			ed modes	
	remote control protocols	supports USB to class (USBTM0 compatibility w	C) and I	egacy mod		
	trigger input EXTernal[1]	differential (0 V	/+3.3 V)		
	reference clock					
	signal level	LVDS				
	frequency	20 MHz				
	permissible total cable length	≤ 5 m				
Ethernet interface	mechanical	-	RJ-45 jack			
only for R&S®NRPxxAN types	power supply	power over Ethernet (PoE) class 1 device		1 device		
	speed		10/100/1000 Mbit/s			
	remote control protocols		VXI11, HiSLIP (high-speed LAN instrument protocol), SCPI-RAW (port 5025)			
	permissible cable length	≤ 100 m				
Trigger-I/O EXTernal2	mechanical	SMB built-in jac	ck			
	impedance					
	input	10 kΩ or 50 Ω	10 kΩ or 50 Ω			
	output	50 Ω	50 Ω			
	signal level					
	input	· · · · · · · · · · · · · · · · · · ·			max1 to +6 V	
	output	≥ 2 V into 50 Ω				
Dimensions (W \times H \times L)	R&S®NRPxxA	48 mm × 30 mi				
		(1.89 in × 1.18				
	R&S®NRPxxAN	73 mm × 26 mi				
		(2.87 in × 1.02		5 in)		
Weight	R&S®NRPxxA	< 0.20 kg (0.44				
	R&S®NRPxxAN	< 0.35 kg (0.77	lb)			

Accessories for R&S®NRP power sensors

Accessories are not approved for the usage in thermal vacuum chambers.

R&S®NRP-ZKU interface cables

The R&S®NRP-ZKU interface cables are used to connect Rohde & Schwarz power sensors described in this data sheet to any standard-conforming USB downstream port (type A receptacle), e.g. on a PC, USB hub or a Rohde & Schwarz instrument.

Connectors	sensor side	8-pin female M12 connector (A-coded)
	host side	USB type A plug
Length	model .02	0.75 m
	model .03	1.50 m
	model .04	3.00 m
	model .05	5.00 m

The R&S®NRP-ZKU interface cables must not be combined with passive USB extension cables as well as commercially available M12 extension cables. Using such extension cables can affect the reliability of the high-speed data transfer.

R&S®NRP-ZK6 interface cables

The R&S®NRP-ZK6 interface cables are used to connect Rohde & Schwarz power sensors described in this data sheet to an R&S®NRP2 power meter, R&S®NRP-Z5 sensor hub or a Rohde & Schwarz instrument providing a 6-pole circular receptacle for R&S®NRP power sensors.

Connectors	sensor side	8-pin female M12 connector (A-coded)
	host side	6-pole circular plug with push-pull locking
Length	model .02	1.50 m
	model .03	3.00 m
	model .04	5.00 m

The R&S®NRP-ZK6 interface cables must not be combined with the R&S®NRP-Z2/-Z3/-Z4 cables as well as commercially available M12 extension cables. Using such extension or adapter cables can affect the reliability of the high-speed data transfer.

R&S®NRP-ZAP1 Gigabit Ethernet switch with Power-over-Ethernet (PoE) capability

The R&S®NRP-ZAP1 Gigabit Ethernet switch with Power-over-Ethernet (PoE) capability can be used to connect up to four R&S®NRPxxSN power sensors to a local area network (LAN) and provide them with operating power.

OEM manufacturer and type		Zyxel GS1110-8HP
Connectivity	LAN ports (PoE)	4 Ethernet RJ-45 ports with PoE power sourcing
		capability (up to 30 W per port, up to 75 W
		overall power budget)
	LAN ports (non-PoE)	4 Ethernet RJ-45 ports
	standard conformance	IEEE 802.3 10BASE-T Ethernet
		IEEE 802.3u 100BASE-TX Ethernet
		IEEE 802.3ab 1000BASE-T Ethernet
		IEEE 802.3af PoE
		IEEE 802.3at PoE+
Power consumption		≤ 90 W
Dimensions (W × D × H)	switch	210 mm × 104 mm ×27 mm
		(8.27 in × 4.09 in × 1.06 in)
Weight	switch	0.55 kg (1.20 lb)
	external power supply and power cord	0.60 kg (1.30 lb)
	switch including power supply, power	1.47 kg (3.20 lb)
	cord and packing	
Environmental specifications	operating temperature range	0 °C to +50 °C
	storage temperature range	–40 °C to +70 °C
	operation humidity range	10 % to 95 % relative humidity, noncondensing

General data

Specifications do not apply to the R&S $^{\! @}\text{NRP-ZAP1}$ Gigabit Ethernet switch.

Temperature ²⁶	R&S®NRPxxS(N), R&S®NRPxxT(N), F	R&S®NRPxxA(N), R&S®NRP-ZKx				
	operating temperature range	0 °C to +50 °C				
	permissible temperature range	–10 °C to +55 °C				
	storage temperature range	–40 °C to +85 °C				
	R&S®NRP33SN-V					
	operating temperature range	0 °C to +50 °C				
	permissible temperature range	–10 °C to +60 °C				
	storage temperature range	–40 °C to +85 °C				
Climatic resistance	damp heat	+25 °C/+55 °C cyclic at 95 % relative humidity				
		with restrictions: noncondensing,				
		in line with EN 60068-2-30				
Mechanical resistance	Vibration	Vibration				
	sinusoidal	5 Hz to 55 Hz, 0.15 mm amplitude,				
		1.8 g at 55 Hz,				
		55 Hz to 150 Hz, 0.5 g constant,				
		in line with EN 60068-2-6				
	random	8 Hz to 650 Hz, 1.9 g (RMS),				
		in line with EN 60068-2-64				
	shock	45 Hz to 2 kHz, max. 40 g shock spectrum,				
		in line with MIL-STD-810E, method 516.4,				
		procedure I				
Air pressure	R&S®NRPxxS(N), R&S®NRPxxT(N), R&S®NRPxxA(N), R&S®NRP-ZKx					
	operating	795 hPa (2000 m) to 1060 hPa				
	transport	566 hPa (4500 m) to 1060 hPa				
	R&S®NRP33SN-V	R&S®NRP33SN-V				
	operating ²⁷	0 hPa to 1060 hPa				
	transport	0 hPa to 1060 hPa				
Electromagnetic compatibility		applied harmonized standards:				
		EN 61326-1				
		EN 61326-2-1				
		EN 55011 (class B)				
Calibration interval	recommended	2 years				

Warranty	power sensors and R&S®NRP-Z5	3 years
	all other items	1 year

Appendix

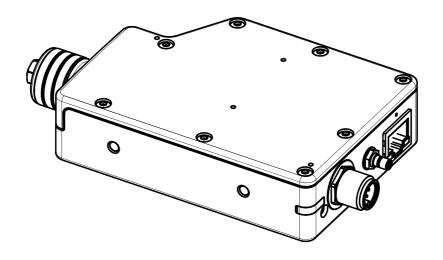
Reading the uncertainty of multipath power sensors for relative power measurements

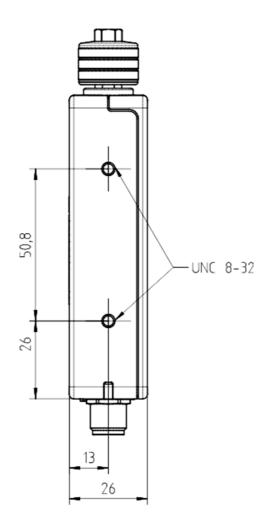
The example shows a level step of approx. 14 dB (-4 dBm \rightarrow +10 dBm) at 1.9 GHz and an ambient temperature of +28 °C for an R&S®NRP8S power sensor. The expanded uncertainty for relative power measurements in this example is 0.093 dB.



Power level 2: +10 dBm

Technical drawings of the R&S $^{\rm @}$ NRP33SN-V multipath power sensor for use in thermal vacuum





Dimensions in mm

Ordering information

Designation	Туре	Order No.
Three-Path Diode Power Sensor		
100 pW to 200 mW, 10 MHz to 8 GHz	R&S®NRP8S	1419.0006.02
100 pW to 200 mW, 10 MHz to 8 GHz, LAN version	R&S®NRP8SN	1419.0012.02
100 pW to 200 mW, 10 MHz to 18 GHz	R&S®NRP18S	1419.0029.02
100 pW to 200 mW, 10 MHz to 18 GHz, LAN version	R&S®NRP18SN	1419.0035.02
100 pW to 200 mW, 10 MHz to 33 GHz	R&S®NRP33S	1419.0064.02
100 pW to 200 mW, 10 MHz to 33 GHz, LAN version	R&S®NRP33SN	1419.0070.02
100 pW to 100 mW, 50 MHz to 40 GHz	R&S®NRP40S	1419.0041.02
100 pW to 100 mW, 50 MHz to 40 GHz, LAN version	R&S®NRP40SN	1419.0058.02
100 pW to 100 mW, 50 MHz to 50 GHz	R&S®NRP50S	1419.0087.02
100 pW to 100 mW, 50 MHz to 50 GHz, LAN version	R&S®NRP50SN	1419.0093.02
100 pW to 200 mW, 10 MHz to 33 GHz, LAN version,	R&S®NRP33SN-V	1419.0129.02
TVAC-compliant		
Thermal Power Sensors		
300 nW to 100 mW, DC to 18 GHz	R&S®NRP18T	1424.6115.02
300 nW to 100 mW, DC to 18 GHz, LAN version	R&S®NRP18TN	1424.6121.02
300 nW to 100 mW, DC to 33 GHz	R&S®NRP33T	1424.6138.02
300 nW to 100 mW, DC to 33 GHz, LAN version	R&S®NRP33TN	1424.6144.02
300 nW to 100 mW, DC to 40 GHz	R&S®NRP40T	1424.6150.02
300 nW to 100 mW, DC to 40 GHz, LAN version	R&S®NRP40TN	1424.6167.02
300 nW to 100 mW, DC to 50 GHz	R&S®NRP50T	1424.6173.02
300 nW to 100 mW, DC to 50 GHz, LAN version	R&S®NRP50TN	1424.6180.02
300 nW to 100 mW, DC to 67 GHz	R&S®NRP67T	1424.6196.02
300 nW to 100 mW, DC to 67 GHz, LAN version	R&S®NRP67TN	1424.6209.02
300 nW to 100 mW, DC to 110 GHz	R&S®NRP110T	1424.6215.02
Average Power Sensors		
100 pW to 200 mW, 8 kHz to 6 GHz	R&S®NRP6A	1424.6796.02
100 pW to 200 mW, 8 kHz to 6 GHz, LAN version	R&S®NRP6AN	1424.6809.02
100 pW to 200 mW, 8 kHz to 18 GHz	R&S®NRP18A	1424.6815.02
100 pW to 200 mW, 8 kHz to 18 GHz, LAN version	R&S®NRP18AN	1424.6821.02
Accessories (cables, additional equipment, etc.)		
USB Interface Cable, length: 0.75 m	R&S®NRP-ZKU	1419.0658.02
USB Interface Cable, length: 1.50 m	R&S®NRP-ZKU	1419.0658.03
USB Interface Cable, length: 3.00 m	R&S®NRP-ZKU	1419.0658.04
USB Interface Cable, length: 5.00 m	R&S®NRP-ZKU	1419.0658.05
Six-Pole Interface Cable, length: 1.50 m	R&S®NRP-ZK6	1419.0664.02
Six-Pole Interface Cable, length: 3.00 m	R&S®NRP-ZK6	1419.0664.03
Six-Pole Interface Cable, length: 5.00 m	R&S®NRP-ZK6	1419.0664.04
Sensor Hub	R&S®NRP-Z5	1146.7740.02
Power over Ethernet (PoE) Switch	R&S®NRP-ZAP1	1419.0829.00
Documentation		
Documentation of Calibration Values	R&S®DCV-1	0240.2187.06
Printout of DCV (in combination with DCV only)	R&S®DCV-ZP	1173.6506.02
Accredited Calibration, for R&S®NRPxxS(N), R&S®NRPxxT(N) and R&S®NRPxxA(N) power sensors	R&S®NRP-ACA	1419.0812.00

Service options		
Extended Warranty, one year	R&S®WE1	Please contact your local
Extended Warranty, two years	R&S®WE2	Rohde & Schwarz sales office.
Extended Warranty with Calibration Coverage, one year	R&S®CW1	
Extended Warranty with Calibration Coverage, two years	R&S®CW2	

Extended warranty with a term of one and two years (WE1 and WE2)

Repairs carried out during the contract term are free of charge ²⁸. Necessary calibration and adjustments carried out during repairs are also covered.

Extended warranty with calibration (CW1 and CW2)

Enhance your extended warranty by adding calibration coverage at a package price. This package ensures that your Rohde & Schwarz product is regularly calibrated, inspected and maintained during the term of the contract. It includes all repairs ²⁸ and calibration at the recommended intervals as well as any calibration carried out during repairs or option upgrades.

For product brochure, see PD 3607.0852.12 and www.rohde-schwarz.com

Footnotes

- 1 Specifications apply to timeslots/gates with a duration of 12.5 % referenced to the signal period (duty cycle 1:8). For other waveforms, the following equation applies: lower measurement limit = lower measurement limit for continuous average mode / √(duty cycle).
- ² With a resolution of 256 pixels.
- 3 Specifications apply to the default transition setting of 0 dB. The transition regions can be shifted by as much as -20 dB using an adequate offset.
- ⁴ Time span prior to triggering, where the trigger signal must be entirely below the threshold level in the case of a positive slope and vice versa in the case of a negative slope.
- ⁵ Specifications expressed as an expanded uncertainty with a confidence level of 95 % (two standard deviations). For calculating zero offsets at higher confidence levels, use the properties of the normal distribution (e.g. 99.7 % confidence level for three standard deviations).
- ⁶ Within one hour after zeroing, permissible temperature change ±1 °C, following a two-hour warm-up of the power sensor.
- ⁷ Two standard deviations at 10.24 s integration time in continuous average mode, with aperture time set to default value. The integration time is defined as the total time used for signal acquisition, i.e. the product of twice the aperture time and the averaging number. Multiplying the noise specifications by √(10.24 s/integration time) yields the noise contribution at other integration times. Using a von Hann window function increases noise by a factor of 1.22.
- Expanded uncertainty (k = 2) for absolute power measurements on CW signals with automatic path selection and the default transition setting of 0 dB. Specifications include calibration uncertainty, linearity and temperature effect. Zero offset, zero drift and measurement noise must additionally be taken into account when measuring low powers. As a rule of thumb, the contribution of zero offset can be neglected for power levels above –40 dBm. The contribution of measurement noise depends on power and integration time and can be neglected below 0.01 dB.

Example: The uncertainty of a power measurement at 3.2 nW (–55 dBm) and 1.9 GHz is to be determined for an R&S®NRP8S. The ambient temperature is +29 °C and the averaging number is set to 32 in the continuous average mode with an aperture time of 20 ms.

Since path 1 is used for the measurement, the typical absolute uncertainty due to zero offset is 28 pW (typical) after external zeroing, which corresponds to a relative measurement uncertainty of

$$10 \lg \frac{3.2 \text{ nW} + 28 \text{ pW}}{3.2 \text{ nW}} dB = 0.038 dB.$$

Using the formula in footnote 7, the absolute noise contribution of path 1 is typically 20 pW × $\sqrt{(10.24 \text{ s}/(32 \times 2 \times 0.02 \text{ s}))}$ = 56.6 pW, which corresponds to a relative measurement uncertainty of

$$10 \lg \frac{3.2 \text{ nW} + 56.6 \text{ pW}}{3.2 \text{ nW}} dB = 0.076 dB$$

Combined with the uncertainty of 0.088 dB for absolute power measurements under the given conditions, the total expanded uncertainty is $\sqrt{0.038^2+0.076^2+0.088^2}$ dB = 0.122 dB.

The contribution of zero drift has been neglected in this case. It must be treated like zero offset if it is relevant for total uncertainty.

Expanded uncertainty (k = 2) for relative power measurements on CW signals of the same frequency with automatic path selection and a default transition setting of 0 dB. For reading the measurement uncertainty diagrams of universal, average and level control sensors, see the Appendix.

Specifications include calibration uncertainty (only if different paths are affected), linearity and temperature effect. Zero offset, zero drift and measurement noise must additionally be taken into account when measuring low powers. As a rule of thumb, the contribution of zero offset can be neglected for power levels above –40 dBm. The contribution of measurement noise depends on power and integration time and can be neglected below 0.01 dB.

Example: The uncertainty of a power step from 0.5 mW (–3 dBm) to 10 nW (–50 dBm) at 5.4 GHz is to be determined for an R&S®NRP8S. The ambient temperature is +20 °C and the averaging number is set to 16 for both measurements in the continuous average mode with an aperture time of 20 ms. For the calculation of total uncertainty, the relative contribution of noise, zero offset and zero drift must be taken into account for both measurements. In this example, all contributions at –3 dBm and the effect of zero drift at –50 dBm have been neglected.

Since path 1 is used for the -50 dBm measurement, the typical absolute uncertainty due to zero offset is 28 pW after external zeroing, which corresponds to a relative measurement uncertainty of

10
$$\lg \frac{10 \text{ nW} + 28 \text{ pW}}{10 \text{ rW}} \text{ dB} = 0.012 \text{ dB}.$$

Using the formula in footnote 7, the absolute noise contribution of path 1 is typically 20 pW $\times \sqrt{(10.24 \text{ s}/(16 \times 2 \times 0.02 \text{ s}))}$ = 80 pW, which corresponds to a relative measurement uncertainty of

10
$$\lg \frac{10 \text{ nW} + 80 \text{ pW}}{10 \text{ nW}} dB = 0.035 \text{ dB}.$$

Combined with the uncertainty of 0.050 dB for relative power measurements under the given conditions, the total expanded uncertainty is $\sqrt{0.012^2+0.035^2+0.050^2}$ dB = 0.062 dB.

- 10 Gamma correction activated
- 11 Preferably used with determined modulation when the aperture time cannot be matched to the modulation period. Compared to a uniform window, measurement noise is about 22 % higher.
- ¹² For measuring the power of periodic bursts based on an average power measurement.

- To increase measurement speed, the power sensor can be operated in buffered mode. In this mode, measurement results are stored in a buffer of user-definable size and then output as a block of data when the buffer is full. To enhance measurement speed even further, the sensor can be set to record the entire series of measurements when triggered by a single event. In this case, the power sensor automatically starts a new measurement as soon as it has completed the previous one.
- 14 For moving mode the maximum burst width of a single burst is 8 s. For repeat mode the mean burst length is limited to 8 s/averaging number.
- ¹⁵ This parameter enables power measurements on modulated bursts. The parameter must be longer in duration than modulation-induced power drops within the burst.
- ¹⁶ To exclude unwanted portions of the signal from the measurement result.
- Specifications are valid for repeat mode, extending from the beginning to the end of all transfers. The actual values depend on the host system, therefore typical values are specified. They have been measured with a USB connection including one USB hub using the USBTMC protocol and an Ethernet network including one PoE switch using the HiSLIP protocol. Measurement times under remote control of the R&S®NRP2 base unit via IEC/IEEE bus are approximately 2.5 ms longer, extending from the start of the measurement up to when the measurement result has been supplied to the output buffer of the R&S®NRP2. For R&S®NRPxxT(N) sensors the specified measurement time is valid for an aperture time less than 100 ms.
- 18 Measurement error referenced to a CW signal of equal power and frequency. Specifications apply up to +20 dBm for automatic path selection or within a subrange to the maximum level of the subrange minus 3 dB.
- ¹⁹ Change of the reflection coefficient (error vector magnitude) referenced to 0 dBm.
- ²⁰ Expanded uncertainty (k = 2) for absolute power measurements on CW signals at the calibration level within a temperature range from +20 °C to +25 °C and at the calibration frequencies. Specifications include zero offset and measurement noise (up to a 2σ value of 0.004 dB). The calibration level is –20 dBm for path 1 and 0 dBm for paths 2 and 3.
- ²¹ Expanded uncertainty (k = 2) for absolute power measurements. Specifications include calibration uncertainty, linearity and temperature effect. Zero offset and measurement noise must additionally be taken into account when measuring low powers, whereas zero drift is negligible over the entire measurement range. As a rule of thumb, the contribution of zero offset can be neglected for power levels above –20 dBm if external zeroing has been applied. The contribution of measurement noise can be neglected below 0.01 dB.

Example: The power to be measured with an R&S®NRP50TN is 5 µW (-23 dBm) at 48 GHz; ambient temperature +29 °C; averaging number set to 64 in continuous average mode with an aperture time of 5 ms (default).

The absolute uncertainty due to zero offset (after external zeroing) is 25 nW, which corresponds to a relative measurement uncertainty of

$$10 \times lg \frac{5 \mu W + \, 25 \, nW}{5 \mu W} = 0.022 \, dB$$

Using the formula in footnote 7, the absolute noise contribution is $25 \text{ nW} \times \sqrt{(10.24 \text{ s}/(64 \times 2 \times 0.005 \text{ s}))} = 100 \text{ nW}$, which corresponds to a relative measurement uncertainty of

$$10 \times lg \frac{5 \mu W + 100 nW}{5 \mu W} = 0.086 dB$$

Combined with the value of 0.149 dB specified for the uncertainty of absolute power measurements at 48 GHz and +29 °C ambient temperature, the total expanded uncertainty is

$$\sqrt{0.149^2 + 0.022^2 + 0.086^2} = 0.173$$
dB

- Expanded uncertainty (k = 2) for relative power measurements on CW signals of the same frequency. Specifications include linearity and temperature effect. Zero offset and measurement noise must additionally be taken into account when measuring low powers, whereas zero drift is negligible over the entire measurement range. As a rule of thumb, the contribution of zero offset can be neglected for power levels above –20 dBm if external zeroing has been applied. The contribution of measurement noise can be neglected below 0.01 dB. See also the example in footnote 9 for taking into account zero offset and noise with relative measurements.
- ²³ Expanded uncertainty (k = 2) for absolute power measurements at the calibration level (0 dBm) within a temperature range from +20 °C to +25 °C and at the calibration frequencies. Specifications include zero offset and measurement noise (up to a 2σ value of 0.004 dB).
- ²⁴ Error of an absolute power measurement with respect to temperature.
- 25 Expanded uncertainty for relative power measurements referenced to the calibration level (0 dBm), excluding zero offset, zero drift and measurement noise.
- ²⁶ The operating temperature range defines the span of ambient temperature in which the instrument complies with specifications. In the permissible temperature range, the instrument is still functioning but compliance with specifications is not warranted.
- ²⁷ To operate the R&S®NRP33SN-V at an air pressure below 795 hPa the sensor has to be mounted onto a temperature-controlled baseplate. In this case the temperature of the baseplate is regarded as the ambient temperature of the sensor.
- ²⁸ Excluding defects caused by incorrect operation or handling and force majeure. Wear-and-tear parts are not included.



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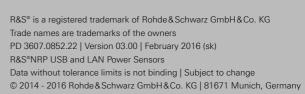
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